## Silicon Switching Diode

- For high-speed switching applications
- Pb-free (RoHS compliant) package ${ }^{1)}$
- Qualified according AEC Q101


BAL74
BAR74


| Type | Package | Configuration | Marking |
| :--- | :--- | :--- | :--- |
| BAL74 | SOT23 | single | JCs |
| BAR74 | SOT23 | single | JBs |

Maximum Ratings at $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :---: | :--- |
| Diode reverse voltage | $V_{\mathrm{R}}$ | 50 | V |
| Peak reverse voltage | $V_{\mathrm{RM}}$ | 50 |  |
| Forward current | $I_{\mathrm{F}}$ | 250 | mA |
| Peak forward current | $I_{\mathrm{FM}}$ | - |  |
| Surge forward current, $t=1 \mu \mathrm{~s}$ | $I_{\mathrm{FS}}$ | 4.5 | A |
| Non-repetitive peak surge forward current | $I_{\mathrm{FSM}}$ | - |  |
| Total power dissipation <br> $T_{\mathrm{S}} \leq 54^{\circ} \mathrm{C}$ | $P_{\text {tot }}$ | 370 | mW |
| Junction temperature | $T_{\mathrm{j}}$ |  |  |
| Storage temperature | $T_{\text {stg }}$ | $-65 \ldots 150$ |  |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :--- | :--- |
| Junction - soldering point ${ }^{2}$ ), BAL74, BAR74 | $R_{\text {thJs }}$ | $\leq 260$ | K/W |

${ }^{1} \mathrm{~Pb}$-containing package may be available upon special request
${ }^{2}$ For calculation of $R_{\mathrm{thJA}}$ please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Values |  |  | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
|  |  | min. | typ. | max. |  |
| DC Characteristics | $V_{(\mathrm{BR})}$ | 50 | - | - | V |
| Breakdown voltage |  |  |  |  |  |
| $I_{(\mathrm{BR})}=100 \mu \mathrm{~A}$ | $\mathrm{I}_{\mathrm{R}}$ |  |  |  | $\mu \mathrm{A}$ |
| Reverse current |  | - | - | 0.1 |  |
| $V_{\mathrm{R}}=50 \mathrm{~V}$ |  | - | - | 100 |  |
| $V_{\mathrm{R}}=50 \mathrm{~V}, T_{\mathrm{A}}=150^{\circ} \mathrm{C}$ | $V_{\mathrm{F}}$ | - | - | 1 | V |
| Forward voltage |  |  |  |  |  |

## AC Characteristics

| Diode capacitance <br> $V_{\mathrm{R}}=0 \mathrm{~V}, f=1 \mathrm{MHz}$ | $C_{\mathrm{T}}$ | - | - | 2 | pF |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Reverse recovery time <br> $I_{\mathrm{F}}=10 \mathrm{~mA}, I_{\mathrm{R}}=10 \mathrm{~mA}$, measured at $I_{\mathrm{R}}=1 \mathrm{~mA}$, <br> $R_{\mathrm{L}}=100 \Omega$ | $t_{\mathrm{rr}}$ | - | - | 4 | ns |

Test circuit for reverse recovery time


Pulse generator: $t_{\mathrm{p}}=100 \mathrm{~ns}, D=0.05$,

$$
t_{\mathrm{r}}=0.6 \mathrm{~ns}, R_{\mathrm{i}}=50 \Omega
$$

Oscillograph: $\mathrm{R}=50 \Omega, t_{r}=0.35 \mathrm{~ns}$,

$$
C \leq 1 p F
$$

Reverse current $l_{\mathrm{R}}=f\left(T_{\mathrm{A}}\right)$
$V_{R}=$ Parameter


Forward current $I_{F}=f\left(V_{F}\right)$


Forward Voltage $V_{\mathrm{F}}=f\left(T_{\mathrm{A}}\right)$
$I_{F}=$ Parameter


Peak forward current $I_{\text {FM }}=f\left(t_{\mathrm{p}}\right)$


Forward current $I_{\mathrm{F}}=f\left(T_{\mathrm{S}}\right)$
BAL74, BAR74


Package Outline


1) Lead width can be 0.6 max. in dambar area

Foot Print


Marking Layout (Example)


Standard Packing
Reel $\varnothing 180 \mathrm{~mm}=3.000$ Pieces/Reel
Reel $\varnothing 330 \mathrm{~mm}=10.000$ Pieces/Reel


Edition 2006-02-01
Published by
Infineon Technologies AG
81726 München, Germany
© Infineon Technologies AG 2007.
All Rights Reserved.

## Attention please!

The information given in this dokument shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie"). With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

## Information

For further information on technology, delivery terms and conditions and prices please contact your nearest Infineon Technologies Office (www.infineon.com).

## Warnings

Due to technical requirements components may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies Office.
Infineon Technologies Components may only be used in life-support devices or systems with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system, or to affect the safety or effectiveness of that device or system.
Life support devices or systems are intended to be implanted in the human body, or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for PIN Diodes category:
Click to view products by Infineon manufacturer:
Other Similar products are found below :
MA45471 MA4SPS502 APD2220-000 APD0810-000 MA4GP907 MA4L032-186 MA4L401-30 MA4P606-258 MA4P7435NM-1091T MA4PK2000 MA4PK2001 MA4PK2004 MADP-007167-12250T MADP-030025-13140P MA4SPS421 MA4PBL027 MA4P404-30 MA4AGFCP910 MA4P7101F-1072T MA4L022-30 MA47047-54 BAR 89-02LRH E6327 UM7108B UM9701 1SV308,L3F UM9301SM 5082-3077 GC4723-42 MA4L011-1088 MSW2001-200 SMP1321-000 M17X1008 UM4010SM UM6002B UM7201SM UM7006A UM7006B UM7108C GC4742-42 MADP-000015-000030 MGPN1503-C01A LXP1004-23-2 MPP4201-206 LXP1004-23-0 MPP4202-206 MPP4205-206 SMP1321-011LF MA4L021-1056 MSW2031-203 MLP7120-11

